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## INFORMATION DISCLOSURE STATEMENT BY APPLICANT

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Complete if Known					
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First Named Inventor	Heiji WATANABE				
Art Unit	2822				
Examiner Name	Tsz K. CHIU				
Attorney Docket Number	Q85504				

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		Country Code <sup>3</sup>	Number <sup>4</sup>	Kind Code <sup>5</sup> (if known)	MM-DD-YYYY	Applicant of Cited Document	Translation <sup>6</sup>
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	/Tsz Chiu/ (01/20/2008)		01/20/2008
Examiner Signature	1132 Ciliui (0112012000)	Date Considered	0 1/20/000

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